Octal bus transceiver; 3-state

Rev. 1 — 21 March 2013

**Product data sheet** 

### 1. General description

The 74AHC245-Q100; 74AHCT245-Q100 is a high-speed Si-gate CMOS device.

The 74AHC245-Q100; 74AHCT245-Q100 is an octal transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions.

The 74AHC245-Q100; 74AHCT245-Q100 features an output enable input ( $\overline{OE}$ ), for easy cascading, and a send and receive direction control input (DIR).

 $\overline{\text{OE}}$  controls the outputs so that the buses are effectively isolated.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Inputs accept voltages higher than V<sub>CC</sub>
- Input levels:
  - For 74AHC245-Q100: CMOS level
  - For 74AHCT245-Q100: TTL level
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

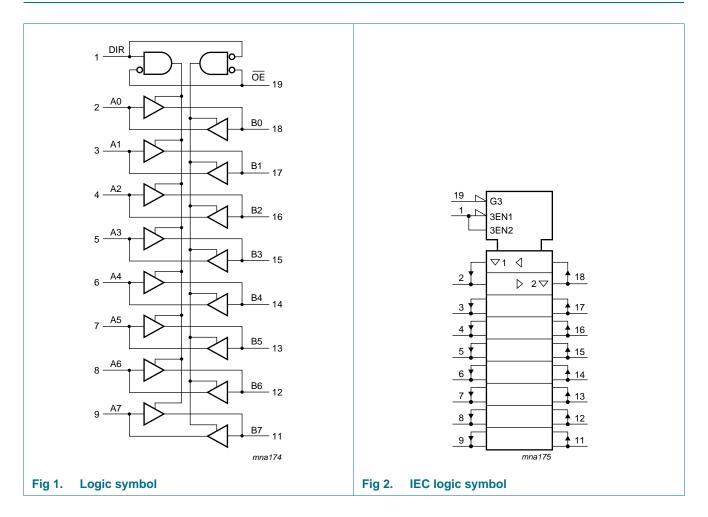


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## 3. Ordering information

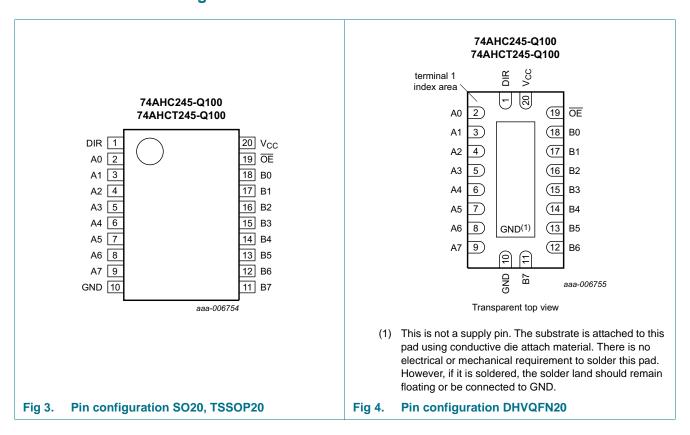
Table 1.Ordering inType number	Package				
	Temperature range	Name	Description	Version	
74AHC245D-Q100	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads;	SOT163-1	
74AHCT245D-Q100			body width 7.5 mm		
74AHC245PW-Q100	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20	SOT360-1	
74AHCT245PW-Q100			leads; body width 4.4 mm		
74AHC245BQ-Q100	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal	SOT764-1	
74AHCT245BQ-Q100			enhanced very thin quad flat package; no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm		

### 4. Functional diagram



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### 5. Pinning information



### 5.2 Pin description

Table 2.Pin description		
Symbol	Pin	Description
DIR	1	direction control input
A0, A1, A2, A3, A4, A5, A6, A7	2, 3, 4, 5, 6, 7, 8, 9	data input/output
GND	10	ground (0 V)
B7, B6, B5, B4, B3, B2, B1, B0	11, 12, 13, 14, 15, 16, 17, 18	data input/output
OE	19	output enable input (active LOW)
V <sub>CC</sub>	20	supply voltage

### 5.1 Pinning

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### 6. Functional description

Table 3.	Function table <sup>[1]</sup>						
Control		Input/output	Input/output				
OE	DIR	An	Bn				
L	L	A = B	inputs				
L	Н	inputs	B = A				
Н	Х	Z	Z				

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

### 7. Limiting values

#### Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	<u>[1]</u> –20	-	mA
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> –20	+20	mA
Ι <sub>Ο</sub>	output current	$V_{\rm O}$ = –0.5 V to (V_{\rm CC} + 0.5 V)	-25	+25	mA
I <sub>CC</sub>	supply current		-	+75	mA
I <sub>GND</sub>	ground current		-75	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$	[2] _	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO20 packages: above 70 °C the value of P<sub>tot</sub> derates linearly at 8 mW/K. For TSSOP20 packages: above 60 °C the value of P<sub>tot</sub> derates linearly at 5.5 mW/K. For DHVQFN20 packages: above 60 °C the value of P<sub>tot</sub> derates linearly at 4.5 mW/K.

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### 8. Recommended operating conditions

Table 5.	Operating conditions					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74AHC2	45-Q100					
V <sub>CC</sub>	supply voltage		2.0	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC}$ = 3.0 V to 3.6 V	-	-	100	ns/V
		$V_{CC}$ = 4.5 V to 5.5 V	-	-	20	ns/V
74AHCT	245-Q100					
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	20	ns/V

### 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC2	45-Q100									
VIH	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
	V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	V	
011	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O}$ = –50 $\mu\text{A};V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O}$ = –50 $\mu\text{A};V_{CC}$ = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		$I_{O}$ = –50 $\mu\text{A};V_{CC}$ = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0 = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_0 = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_0 = 50 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu A; \ V_{CC} = 3.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 4.0 mA; $V_{CC}$ = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		$I_{O} = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V

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#### Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		_40 °C ∙	to +85 °C	–40 °C t	o +125 °C	Un
			Min	Тур	Max	Min	Max	Min	Max	
l <sub>l</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
l <sub>oz</sub>	OFF-state output current		-	-	±0.25	-	±2.5	-	±10.0	μA
lcc	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	4.0	-	40	-	80	μA
Cı	input capacitance	$V_{I} = V_{CC} \text{ or } GND$	-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	рF
74AHCT	245-Q100									
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V <sub>он</sub>	HIGH-level	$V_{\text{I}}$ = $V_{\text{IH}}$ or $V_{\text{IL}};$ $V_{\text{CC}}$ = 4.5 V								
output voltage	I <sub>O</sub> = -50 μA	4.4	4.5	-	4.4	-	4.4	-	V	
		I <sub>O</sub> = -8.0 mA	3.94	-	-	3.80	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
lı	input leakage current	$V_I = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$	-	-	0.1	-	1.0	-	2.0	μA
I <sub>OZ</sub>	OFF-state output current		-	-	±0.25	-	±2.5	-	±10.0	μA
I <sub>CC</sub>	supply current		-	-	4.0	-	40	-	80	μA
∆l <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V};$ other pins at $V_{CC}$ or GND; $I_O = 0 \text{ A}; V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	1.35	-	1.5	-	1.5	m/
CI	input capacitance	$V_I = V_{CC}$ or GND	-	3	10	-	10	-	10	рF
Co	output capacitance		-	4	-	-	-	-	-	pF

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### **10.** Dynamic characteristics

#### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

Symbol	Parameter	Conditions			25 °C		_40 °C	to +85 °C	–40 °C 1	o +125 °C	Uni
				Min	Typ[1]	Max	Min	Max	Min	Max	
74AHC2	45-Q100										
pd	propagation delay	An to Bn; Bn to An; see <u>Figure 5</u>	[2]								
		$V_{CC}$ = 3.0 V to 3.6 V									
		C <sub>L</sub> = 15 pF		-	5.0	8.4	1.0	10.0	1.0	10.5	ns
		C <sub>L</sub> = 50 pF		-	6.5	11.9	1.0	13.5	1.0	15.0	ns
		$V_{CC}$ = 4.5 V to 5.5 V									
		C <sub>L</sub> = 15 pF		-	3.5	5.5	1.0	6.5	1.0	7.0	ns
		C <sub>L</sub> = 50 pF			5.0	7.5	1.0	8.5	1.0	9.5	ns
t <sub>en</sub> enable time	OE to An; OE to Bn; signal name DIR; see <u>Figure 6</u>	[3]									
		$V_{CC}$ = 3.0 V to 3.6 V									
		C <sub>L</sub> = 15 pF		-	6.5	13.2	1.0	15.5	1.0	16.5	ns
		C <sub>L</sub> = 50 pF		-	9.0	16.7	1.0	19.0	1.0	21.0	ns
		$V_{CC}$ = 4.5 V to 5.5 V									
		C <sub>L</sub> = 15 pF		-	4.0	8.5	1.0	10.0	1.0	11.0	ns
		C <sub>L</sub> = 50 pF		-	5.0	10.6	1.0	12.0	1.0	13.5	ns
disable time	disable time	OE to An; OE to Bn; signal name DIR; see <u>Figure 6</u>	<u>[4]</u>								
		$V_{CC}$ = 3.0 V to 3.6 V									
		C <sub>L</sub> = 15 pF		-	7.5	12.5	1.0	15.5	1.0	16.0	ns
		$C_L = 50 \text{ pF}$		-	10.0	15.8	1.0	18.0	1.0	20.0	ns
		$V_{CC}$ = 4.5 V to 5.5 V									
		C <sub>L</sub> = 15 pF		-	4.5	7.8	1.0	9.2	1.0	10.0	ns
		C <sub>L</sub> = 50 pF		-	6.0	9.7	1.0	11.0	1.0	12.5	ns
C <sub>PD</sub>	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V <sub>I</sub> = GND to V <sub>CC</sub>	[5]	-	12	-	-	-	-	-	pF
74AHCT	245-Q100; V <sub>C</sub>	<sub>C</sub> = 4.5 V to 5.5 V									
t <sub>pd</sub>	propagation delay	An to Bn; Bn to An; see <u>Figure 5</u>	[2]								
		C <sub>L</sub> = 15 pF		-	3.5	7.7	1.0	8.5	1.0	10.0	ns
		C <sub>L</sub> = 50 pF		-	4.5	8.7	1.0	9.5	1.0	11.0	ns
en	enable time	OE to An; OE to Bn; signal name DIR; see <u>Figure 6</u>	<u>[3]</u>								
		C <sub>L</sub> = 15 pF		-	5.0	13.8	1.0	15.0	1.0	17.5	ns
		C <sub>L</sub> = 50 pF		-	6.0	14.8	1.0	16.0	1.0	18.5	ns
	45_Q100	All 1. C			nent is subject	to logal disc	laimara		© N	XP B.V. 2013. All righ	to rook

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Symbol	Parameter	Conditions		25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
t <sub>dis</sub> disable time		OE to An; OE to Bn;       [4]         signal name DIR;       see Figure 6								
		C <sub>L</sub> = 15 pF	-	5.0	14.4	1.0	15.5	1.0	18.0	ns
		C <sub>L</sub> = 50 pF	-	6.0	15.4	1.0	16.5	1.0	19.5	ns
C <sub>PD</sub>	power dissipation capacitance	$f_i = 1 \text{ MHz};$ [5] V <sub>I</sub> = GND to V <sub>CC</sub>	-	15	-	-	-	-	-	pF

#### Table 7. Dynamic characteristics ... continued

[1] Typical values are measured at nominal supply voltage ( $V_{CC} = 3.3$  V and  $V_{CC} = 5.0$  V).

#### [2] $t_{pd}$ is the same as $t_{PLH}$ and $t_{PHL}$ .

- [3]  $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ .
- [4]  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$ 

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

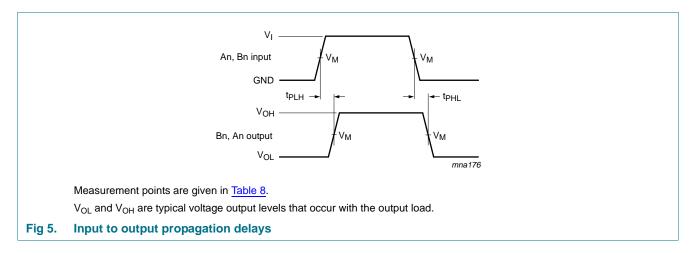
 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

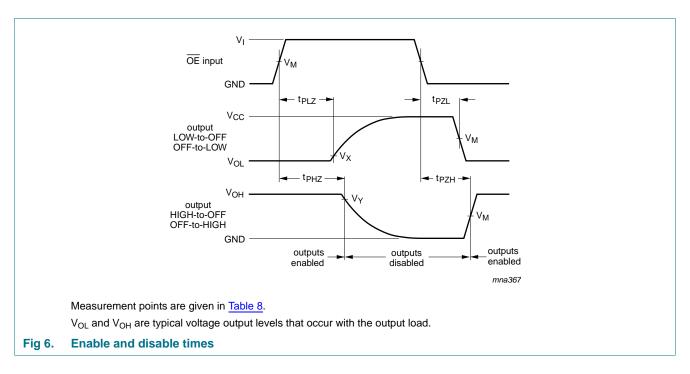
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

### 10.1 Waveforms



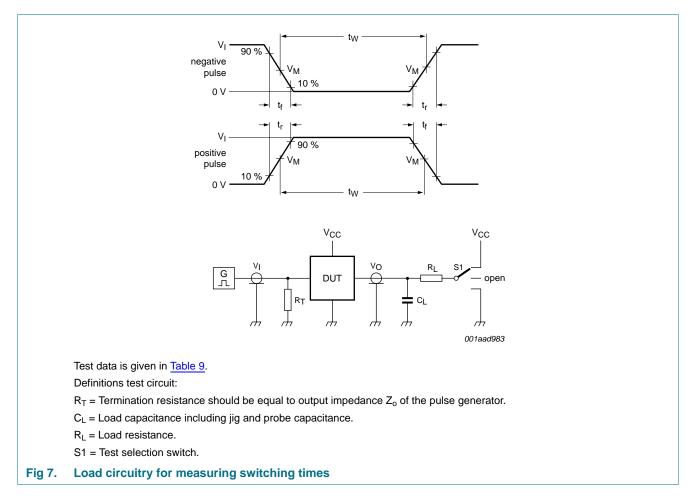
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#### Table 8.Measurement points

Туре	Input	Output	Output					
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>				
74AHC245-Q100	$0.5\times V_{CC}$	$0.5 \times V_{\text{CC}}$	V <sub>OL</sub> + 0.3 V	$V_{OH} - 0.3 \ V$				
74AHCT245-Q100	1.5 V	$0.5\times V_{CC}$	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V				

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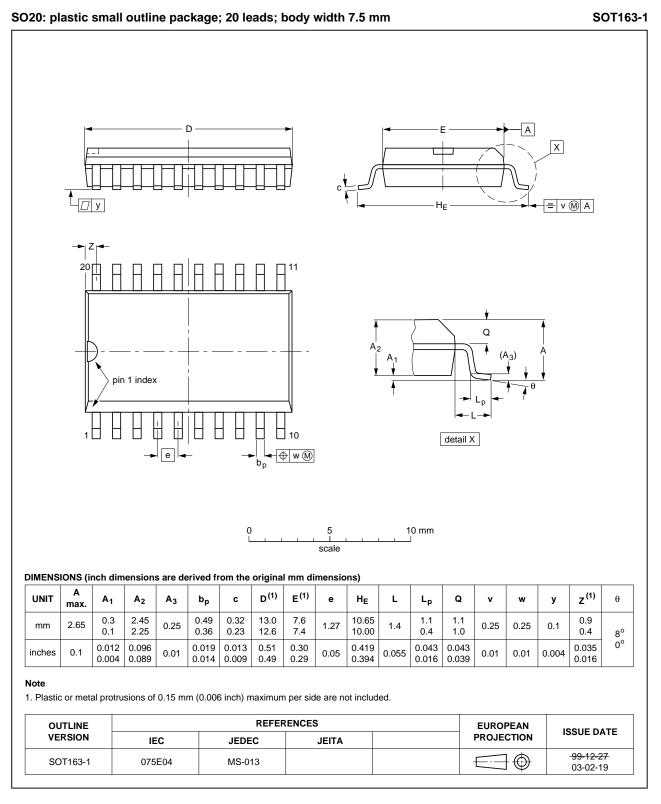


#### Table 9. Test data

Туре	Input		Load	Load		S1 position		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>	
74AHC245-Q100	V <sub>CC</sub>	$\leq$ 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>	
74AHCT245-Q100	3.0 V	$\leq$ 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>	

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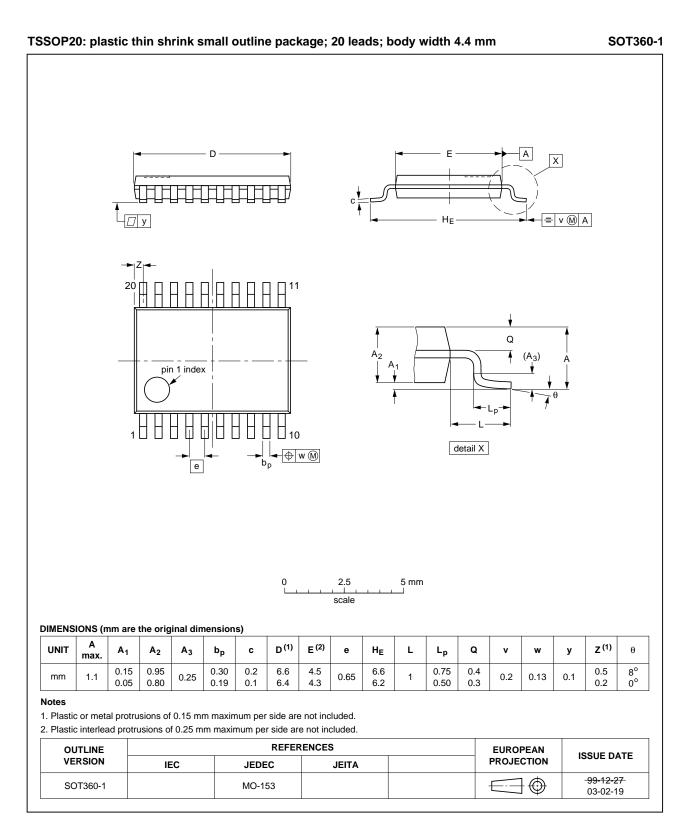
### 11. Package outline



#### Fig 8. Package outline SOT163-1 (SO20)

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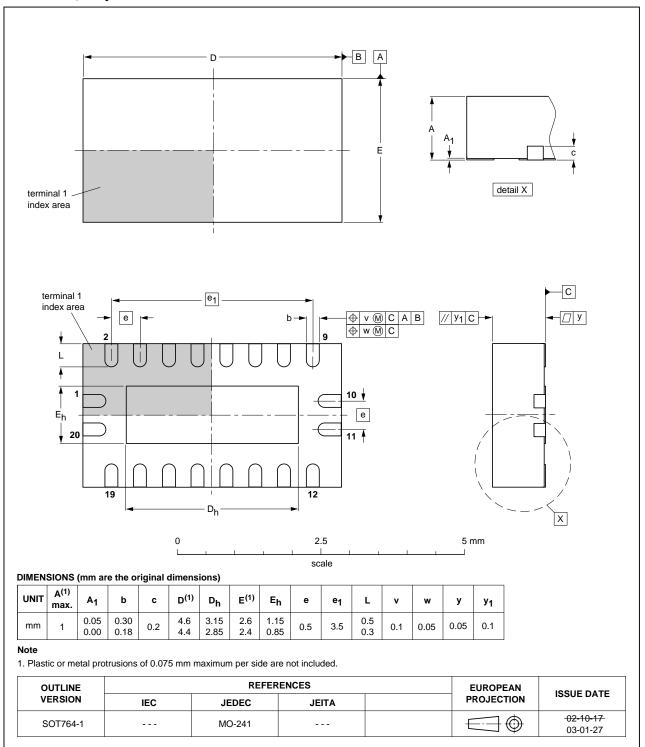
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#### Fig 9. Package outline SOT360-1 (TSSOP20)

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DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

#### Fig 10. Package outline SOT764-1 (DHVQFN20)

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### **12. Abbreviations**

AcronymDescriptionCDMCharged Device ModelCMOSComplementary Metal-Oxide SemiconductorDUTDevice Under TestESDElectroStatic DischargeHBMHuman Body ModelMMMachine ModelMILMilitaryTTLTransistor-Transistor Logic	Table 10.	Abbreviations
CMOSComplementary Metal-Oxide SemiconductorDUTDevice Under TestESDElectroStatic DischargeHBMHuman Body ModelMMMachine ModelMILMilitary	Acronym	Description
DUTDevice Under TestESDElectroStatic DischargeHBMHuman Body ModelMMMachine ModelMILMilitary	CDM	Charged Device Model
ESDElectroStatic DischargeHBMHuman Body ModelMMMachine ModelMILMilitary	CMOS	Complementary Metal-Oxide Semiconductor
HBM     Human Body Model       MM     Machine Model       MIL     Military	DUT	Device Under Test
MM     Machine Model       MIL     Military	ESD	ElectroStatic Discharge
MIL Military	HBM	Human Body Model
	MM	Machine Model
TTI Transistor-Transistor Logic	MIL	Military
	TTL	Transistor-Transistor Logic

## 13. Revision history

Table 11. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT245_Q100 v.1	20130321	Product data sheet	-	-

### 14. Legal information

#### 14.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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